

Technical documentation

[TPSM82810,](https://www.tij.com.cn/product/cn/tpsm82810?qgpn=tpsm82810) [TPSM82813](https://www.tij.com.cn/product/cn/tpsm82813?qgpn=tpsm82813)

ZHCSKB4A – SEPTEMBER 2019 – REVISED DECEMBER 2020

具有集成电感器和频率同步功能的 **TPSM8281x 2.75V** 至 **6V** 输入 **4A** 和 **3A** 降压 **MicroSiP™** 电源模块

1 特性

- 输入电压范围 : 2.75V 至 6V
- 输出电压范围:0.6V 至 5.5V
- 可调和可同步开关频率为 1.8MHz 至 4MHz
- 展频时钟 可选

TEXAS

INSTRUMENTS

- 可选强制 PWM 或 PFM/PWM 运行
- 输出电压精度为 ±1%(PWM 运行)
- 具有窗口比较器的电源正常输出
- 100% 占空比
- 输出放电
- 精密使能输入可实现
	- 用户定义的欠压锁定
	- 准确排序
- 15µA 静态电流(典型值)
- 可调软启动或跟踪

2 应用

- [光学模块、数据中心互连](http://www.ti.com/solution/optical-module)
- [信号测量、源生成、仪表](https://www.ti.com/applications/industrial/test-measurement/overview.html)
- [患者监护和诊断](https://www.ti.com/applications/industrial/medical/overview.html)
- [无线基础设施](https://www.ti.com/applications/communications-equipment/wireless-infrastructure/overview.html)
- 加固型通信:[传感器、成像和雷达](http://www.ti.com/applications/industrial/aerospace-defense/overview.html)

3 说明

TPSM8281x 是具有集成电感器、引脚对引脚兼容的 3A 和 4A 高效、易于使用的同步降压直流/直流电源模 块系列。它们基于固定频率峰值电流模式控制拓扑,用 于具有高功率密度和易用性要求的电信、测试和测量以 及医疗应用领域。低阻开关可在高温环境下支持高达 4A 的持续输出电流。用户可通过外部方式在 1.8MHz 至 4MHz 范围内调节开关频率,亦可在该频率范围内 将其同步至外部时钟 。 在 PWM/PFM 模式下 , TPSM8281x 会在轻负载情况下自动进入省电模式,从 而在整个负载范围内维持高效率。TPSM8281x 可在 PWM 模式下提供 1% 的输出电压精度,这有助于实现 具有高输出电压精度的电源设计。SS/TR 引脚可设置 启动时间或跟踪向外部源提供的输出电压。此特性可实 现不同电源轨的外部定序并限制启动期间的浪涌电流。

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。

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注:以前版本的页码可能与当前版本的页码不同

5 Device Comparison Table

6 Pin Configuration and Functions

图 **6-1. 14-pin** μ**SiL Package (Top View)**

表 **6-1. Pin Functions**

7 Specifications

7.1 Absolute Maximum Ratings

Over operating junction temperature range (unless otherwise noted) (1)

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

(1) The values given for all the capacitors in the table are effective capacitance, which includes the DC bias effect. Due to the DC bias effect of ceramic capacitors, the effective capacitance is lower than the nominal value when a voltage is applied. Please check the manufacturer´s DC bias curves for the effective capacitance vs DC voltage applied. Please see [Section 9.3.3](#page-9-0) about the output capacitance vs compensation setting and output voltage.

7.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](https://www.ti.com/lit/pdf/spra953) application report and [Section 12.3 - Thermal Consideration](#page-21-0).

7.5 Electrical Characteristics

Over operating junction temperature (T」= -40 °C to +125 °C) and V_{IN} = 2.75 V to 6 V. Typical values at V_{IN} = 5 V and T」= 25 °C. (unless otherwise noted)

7.5 Electrical Characteristics (continued)

Over operating junction temperature (T」= -40 °C to +125 °C) and V_{IN} = 2.75 V to 6 V. Typical values at V_{IN} = 5 V and T」= 25 °C. (unless otherwise noted)

(1) This is the static current limit. It can be temporarily higher in applications due to internal propagation delay (see *[Current Limit And](#page-12-0) [Short Circuit Protection section](#page-12-0)*).

7.6 Typical Characteristics

8 Parameter Measurement Information

8.1 Schematic

图 **8-1. Measurement Setup for TPSM8281x**

表 **8-1. List of Components**

(1) See the *[Third-party Products Disclaimer](#page-23-0)*.

9 Detailed Description

9.1 Overview

The TPSM8281x synchronous switch mode DC/DC converter power modules are based on a fixed-frequency peak current-mode control topology. The control loop is internally compensated. To optimize the bandwidth of the control loop to the wide range of output capacitance that can be used with the TPSM8281x, one of three internal compensation settings can be selected. See 节 *[9.3.3](#page-9-0)*. The compensation setting is selected either by a resistor from COMP/FSET to GND, or by the logic state of this pin. The regulation network achieves fast and stable operation with small external components and low-ESR ceramic output capacitors.

The devices support fixed-frequency forced PWM operation with the MODE/SYNC pin tied to a logic high level. When the MODE/SYNC pin is set to a logic low level, the device operates in power save mode (PFM) at lowoutput currents and automatically transitions to fixed-frequency PWM mode at higher output currents. In PFM mode, the switching frequency decreases linearly based on the load to sustain high efficiency down to very low output currents. The device can be synchronized to an external clock signal in a range from 1.8 MHz to 4 MHz applied to the MODE/SYNC pin.

9.2 Functional Block Diagram

9.3 Feature Description

9.3.1 Precise Enable (EN)

The TPSM8281x starts operation when the rising EN threshold is exceeded. For proper operation, the EN pin must be terminated and must not be left floating. Pulling the EN pin low forces the device into shutdown. In this mode, the internal high-side and low-side MOSFETs are turned off and the entire internal control circuitry is switched off. The voltage applied at the EN pin of the TPSM8281x is compared to a fixed threshold of 1.1 V for a rising voltage.

The enable input threshold for a falling edge is typically 100 mV lower than the rising edge threshold. The Precise Enable input provides a user-programmable undervoltage lockout by adding a resistor divider to the input of the EN pin. The Precise Enable input also allows you to drive the pin by a slowly changing voltage and enables the use of an external RC network to achieve a precise power-up delay. See the *[Achieving a Clean](https://www.ti.com/lit/SLYT730) [Start-up by Using a DC/DC Converter with a Precise Enable-pin Threshold Technical Brief](https://www.ti.com/lit/SLYT730)* for more details.

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9.3.2 Output Discharge

The purpose of the discharge function is to ensure a defined down-ramp of the output voltage when the device is disabled and keep the output voltage close to 0 V when the device is off. The output discharge feature is only active once the TPSM8281x has been enabled at least once since the supply voltage was applied. The discharge function is enabled as soon as the device is disabled, in thermal shutdown, or in undervoltage lockout. The minimum supply voltage required for the discharge function to remain active is typically 1 V.

9.3.3 COMP/FSET

This pin sets two different parameters independently:

- Internal compensation settings for the control loop (three settings available)
- The switching frequency in PWM mode from 1.8 MHz to 4 MHz

A resistor from COMP/FSET to GND changes the compensation as well as the switching frequency. The change in compensation adapts the device to different values of output capacitance. The resistor must be placed close to the pin to keep the parasitic capacitance on the pin to a minimum. The compensation setting is set after enabling the converter, so a change in the resistor during operation only has an effect on the switching frequency but not on the compensation.

To save external components, the pin can also be directly tied to VIN or GND to set a pre-defined switching frequency and compensation. Do not leave the pin floating.

The switching frequency must be selected based on the maximum input voltage and the output voltage to meet the specifications for the minimum on-time. Using $V_{IN} = 5.5$ V and $V_{OUT} = 1.1$ V as an example, the minimum duty cycle given with Equation 1 is 0.2, which results in a maximum switching frequency of 2.67 MHz according to Equation 2.

$$
D_{\min} = \frac{V_{OUT}}{V_{IN,max}}
$$

\n
$$
f_{s,max} = \frac{1}{t_{on,min} \times D_{\min}}
$$
\n(1)

The compensation range has to be chosen based on the minimum effective capacitance used. The capacitance can be increased from the minimum value as given in $\frac{1}{6}$ [9-1](#page-10-0) up to the maximum of 470 µF in all of the three compensation ranges. If the capacitance of an output changes during operation, for example, when load switches are used to connect or disconnect parts of the circuitry, the compensation has to be chosen for the minimum capacitance on the output. With large output capacitance, the compensation must be done based on that large capacitance to get the best load transient response. Compensating for large output capacitance but placing less capacitance on the output can lead to instability.

The switching frequency for the different compensation setting is determined by the following equations.

For compensation (comp) setting 1:

$$
R_{CF}(k\Omega) = \frac{18MHz \cdot k\Omega}{f_s(MHz)}
$$

For compensation (comp) setting 2:

$$
R_{CF}(k\Omega) = \frac{60MHz \cdot k\Omega}{f_s(MHz)}
$$

For compensation (comp) setting 3:

(2)

(3)

(4)

(5)

表 **9-1. Switching Frequency and Compensation**

Refer to 节 *[10.2.2.4](#page-15-0)* for further details on the output capacitance required depending on the output voltage. All values are the effective value of capacitance.

A too high resistor value for R_{CF} is read as "tied to V_{IN} ", and a value below the lowest range as "tied to GND". The minimum output capacitance in $\frac{1}{6}$ 9-1 is for capacitors close to the output of the device. If the capacitance is distributed, a lower compensation setting can be required.

9.3.4 MODE/SYNC

When MODE/SYNC is set low, the device operates in PWM or PFM mode, depending on the output current. The MODE/SYNC pin forces PWM mode when set high. The pin also allows you to apply an external clock in a frequency range from 1.8 MHz to 4 MHz for external synchronization. When an external clock is applied, the device operates in PWM mode. As with the switching frequency selection, the specification for the minimum ontime has to be observed when applying the external clock signal. When using external synchronization, it is recommended to set the internal switching frequency as set by R_{CF} to a similar value as the externally applied clock. This ensures that, if the external clock fails, the switching frequency stays in the same range and the settling time to the internal clock is reduced. When there is no resistor from COMP/FSET to GND, but the pin is pulled high or low, external synchronization is not possible. An internal PLL allows you to change from an internal clock to external clock during operation. The synchronization to the external clock is done on the falling edge of the applied clock to the rising edge of the internal SW pin. The MODE/SYNC pin can be changed during operation.

9.3.5 Spread Spectrum Clocking (SSC) - TPSM8281xS

These devices offer spread spectrum clocking, where the switching frequency is randomly changed in PWM mode when the internal clock is used. The frequency variation is typically between the nominal switching frequency and up to 288 kHz above the nominal switching frequency. When the device is externally synchronized, the TPSM8281xS follows the external clock and the internal spread spectrum block is turned off. SSC is also disabled during soft start.

9.3.6 Undervoltage Lockout (UVLO)

If the input voltage drops, the undervoltage lockout prevents mis-operation of the device by switching off both the MOSFETs. The device is fully operational for voltages above the rising UVLO threshold and turns off if the input voltage goes below the falling threshold.

9.3.7 Power-Good Output (PG)

The device has a power good output with window comparator. The PG pin goes high impedance once the FB pin voltage is above 95% and less than 107% of the nominal voltage, and is driven low once the voltage falls below typically 90% or higher than 110% of the nominal voltage. $\bar{\mathcal{R}}$ 9-2 shows the typical PG pin logic. The PG pin is an open-drain output and is specified to sink up to 2 mA. The power good output requires a pullup resistor connected to any voltage rail less than VIN. The PG signal can be used for sequencing of multiple rails by connecting to the EN pin of other converters. If not used, the PG pin can be left floating or connected to GND.

The PG pin has a 40- μ s deglitch time on the falling edge.

9.3.8 Thermal Shutdown

The junction temperature (T $_{\rm J}$) of the device is monitored by an internal temperature sensor. If T $_{\rm J}$ exceeds 170°C (typ), the device goes into thermal shutdown. Both the high-side and low-side power FETs are turned off and PG goes low. When T $_{\textrm{\scriptsize{J}}}$ decreases below the hysteresis amount of typically 15°C, the converter resumes normal operation, beginning with soft start. During PFM, the thermal shutdown is not active.

9.4 Device Functional Modes

9.4.1 Pulse Width Modulation (PWM) Operation

The TPSM8281x has two operating modes: Forced PWM mode and PFM/PWM mode.

With the MODE/SYNC pin set to high, the TPSM8281x operates with pulse width modulation in continuous conduction mode (CCM). The switching frequency is either defined by a resistor from the COMP/FSET pin to GND or by an external clock signal applied to the MODE/SYNC pin.

9.4.2 Power Save Mode Operation (PFM/PWM)

When the MODE/SYNC pin is low, power save mode is allowed. The device operates in PWM mode as long as the peak inductor current is above the PFM threshold of about 1.2 A. When the peak inductor current drops below the PFM threshold, the device starts to skip switching pulses.

In power save mode, the switching frequency decreases linearly with the load current to maintain high efficiency. The linear behavior of the switching frequency in power save mode is shown in \boxtimes 9-1.

图 **9-1. Switching frequency versus Output Current (VIN = 5 V, VOUT = 1.8 V)**

9.4.3 100% Duty-Cycle Operation

The device offers a low input-to-output voltage differential by entering 100% duty cycle mode. When the minimum off-time of typically 30 ns is reached, the TPSM8281x skips switching cycles while it approaches 100% mode. In 100% mode, the high-side MOSFET switch is constantly turned on. This is particularly useful in batterypowered applications to achieve longest operation time by taking full advantage of the whole battery voltage range. The minimum input voltage to maintain a minimum output voltage is given by:

$$
V_{IN \text{(min)}} = V_{OUT \text{(min)}} + I_{OUT} \times R_{DP} \tag{6}
$$

where

- R_{DP} is the resistance from V_{IN} to V_{OUT} , which includes the high-side MOSFET on-resistance and DC resistance of the inductor
- $V_{OUT (min)}$ is the minimum output voltage the load can accept

9.4.4 Current Limit and Short Circuit Protection

The TPSM8281x is protected against overload and short circuit events. If the inductor current exceeds the current limit I_{LIMH}, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current. The high-side MOSFET turns on again only if the current in the low-side MOSFET has decreased below the low-side current limit. Due to internal propagation delays, the actual current can exceed the static current limit. The dynamic current limit is given as:

$$
I_{peak(typ)} = I_{LIMH} + \frac{V_L}{L} \cdot t_{PD}
$$
\n(7)

where

- I_{LIMH} is the static current limit, as specified in the electrical characteristics
- L is the effective inductance (typically 470 nH)
- V_L is the voltage across the inductor (V_{IN} V_{OUT})
- t_{PD} is the internal propagation delay of typically 50 ns

The dynamic peak current is calculated as follows:

$$
I_{peak(typ)} = I_{LIMH} + \frac{V_{IN} - V_{OUT}}{L} \cdot 50ns
$$

(8)

The low-side MOSFET also contains a negative current limit to prevent excessive current from flowing back through the inductor to the input. If the low-side sinking current limit is exceeded, the low-side MOSFET is turned off. In this scenario, both MOSFETs are off until the start of the next cycle. The negative current limit is only active in Forced PWM mode.

9.4.5 Soft Start / Tracking (SS/TR)

The internal soft-start circuitry controls the output voltage slope during start-up. This avoids excessive inrush current and ensures a controlled output voltage rise time. It also prevents unwanted voltage drops from high impedance power sources or batteries. When EN is set high, the device starts switching after a delay of about 200 μ s. Then V_{OUT} rises with a slope controlled by an external capacitor connected to the SS/TR pin.

A capacitor connected from SS/TR to GND is charged with 2.5 µA by an internal current source during soft start until it reaches the reference voltage of 0.6 V. After reaching 0.6 V, the SS/TR pin voltage is clamped internally while the SS/TR pin voltage keeps rising to a maximum of about 3.3 V. The capacitance required to set a certain ramp-time (t_{ramp}) is:

$$
Css[nF] = \frac{2.5\mu A \cdot \text{tramp}\left[ms\right]}{0.6V}
$$

(9)

Leaving the SS/TR pin un-connected provides the fastest start-up ramp of 150 µs typically. If the device is set to shutdown (EN = GND), undervoltage lockout, or thermal shutdown, an internal resistor pulls the SS/TR pin to GND to ensure a proper low level. Returning from those states causes a new start-up sequence.

A voltage applied at the SS/TR pin can also be used to track a master voltage. The output voltage follows this voltage in both directions up and down in forced PWM mode. In PFM mode, the output voltage decreases based on the load current. An external voltage applied on SS/TR is internally clamped to the feedback voltage (0.6 V). It is recommended to set the final value of the external voltage on SS/TR to be slightly above 0.6 V to make sure the device operates with its internal reference voltage when the power-up sequencing is finished. See 节 *[10.3.1](#page-19-0)*.

10 Application and Implementation

Note

以下应用部分的信息不属于 TI 组件规范,TI 不担保其准确性和完整性。客户应负责确定 TI 组件是否适 用于其应用。客户应验证并测试其设计,以确保系统功能。

10.1 Application Information

The TPSM8281x are synchronous step-down converter power modules. The required power inductor is integrated inside the TPSM8281x. The inductor is shielded and has an inductance of 470 nH with approximately a ±20% tolerance. The TPSM82810 and TPSM82813 are pin-to-pin and BOM-to-BOM compatible, differing only in their rated output current.

10.2 Typical Application

图 **10-1. Typical Application Schematic**

10.2.1 Design Requirements

The design guidelines provide a component selection to operate the device within the recommended operating conditions.

10.2.2 Detailed Design Procedure

10.2.2.1 Programming the Output Voltage

The output voltage of the TPSM8281x is adjustable. Choose resistors R1 and R2 to set the output voltage within a range of 0.6 V to 5.5 V according to Equation 10. To keep the feedback (FB) net robust from noise, set R2 equal to or lower than 100 kΩ to have at least 6 µA of current in the voltage divider. Lower values of FB resistors achieve better noise immunity, and lower light load efficiency, as explained in the *[Design Considerations for a](https://www.ti.com/lit/pdf/SLYT469) [Resistive Feedback Divider in a DC/DC Converter Technical Brief](https://www.ti.com/lit/pdf/SLYT469)*.

$$
R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1\right) = R2 \times \left(\frac{V_{OUT}}{0.6V} - 1\right)
$$

(10)

10.2.2.2 Feedforward capacitor

A feedforward capacitor (C_{FF}) is recommended in parallel with R_1 in order to improve the transient response. Regardless of the FB resistor values, the C_{FF} value should always be 10 pF.

10.2.2.3 Input Capacitor

For most applications, a 22-µF nominal ceramic capacitor is recommended. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. A X7R or X7T multilayer ceramic capacitor (MLCC) is recommended for best filtering and must be placed between VIN and GND as close as possible to those pins. For applications with ambient temperatures below 85°C, a capacitor with X5R dielectric can be used. Ceramic capacitors have a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitor carefully in combination with considering its package size and voltage rating. The minimum required input capacitance is 5 µF.

10.2.2.4 Output Capacitor

The architecture of the TPSM8281x allows the use of ceramic output capacitors which have low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get a narrow capacitance variation with temperature, it is recommended to use an X7R or X7T dielectric. At temperatures below 85°C, an X5R dielectric can be used.

Using a higher capacitance value has advantages like smaller voltage ripple and a tighter DC output accuracy in power save mode. By changing the device compensation with a resistor from COMP/FSET to GND, the device can be compensated in three steps based on the minimum capacitance used on the output. The maximum capacitance is 470 µF in any of the compensation settings. The minimum capacitance required on the output depends on the compensation setting and output voltage as shown in $\overline{\mathcal{R}}$ [9-1](#page-10-0). For output voltages below 1 V, the minimum required capacitance increases linearly from 32 μ F at 1 V to 53 μ F at 0.6 V with the compensation setting for smallest output capacitance. Other compensation settings scale the same. Ceramic capacitors have a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitor carefully in combination with considering its package size and voltage rating.

10.2.2.5 Application Curves

 T_A = 25°C, V_{IN} = 5 V, V_{OUT} = 1.8 V, 1.8 MHz, PWM mode, BOM = $\frac{1}{\mathcal{R}}$ [8-1](#page-7-0) unless otherwise noted.

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10.3 System Examples

10.3.1 Voltage Tracking

The SS/TR pin is externally driven by another voltage source to achieve output voltage tracking. The application circuit is shown in Figure 10-21. From $0 \vee$ to 0.6 V, the internal reference voltage to the internal error amplifier follows the SS/TR pin voltage. When the SS/TR pin voltage is above 0.6 V, the voltage tracking is disabled and the FB pin voltage is regulated at 0.6 V. The device achieves ratiometric or coincidental (simultaneous) output tracking, as shown in Figure 10-22.

The R2 value should be set properly to achieve accurate voltage tracking by taking the 2.5- μ A charging current into account. 1 kΩ or smaller is a sufficient value for R2. For decreasing SS/TR pin voltage, the device does not sink current from the output when the device is in PFM mode. The resulting decrease of the output voltage can be slower than the SS/TR pin voltage if the load is light. When driving the SS/TR pin with an external voltage, do not exceed the voltage rating of the SS/TR pin which is VIN+0.3 V.

图 **10-22. Output Voltage Tracking**

10.3.2 Synchronizing to an External Clock

The TPSM8281x can be synchronized by applying a clock on the MODE/SYNC pin. There is no need for any additional circuitry. See Figure 10-23. The clock can be applied, changed, and removed during operation. The value of the R_{CF} resistor is recommended to be chosen such that the internally defined frequency and the externally-applied frequency are close to each other in order to have a fast settling time to the external clock. Synchronizing to a clock is not possible, if the COMP/FSET pin is connected to Vin or GND. Figure 10-24 and Figure 10-25 show the external clock being applied and removed. When an external clock is applied, the device operates in PWM mode.

图 **10-23. Frequency Synchronization**

11 Power Supply Recommendations

The TPSM8281x device family has no special requirements for its input power supply. The output current of the input power supply needs to be rated according to the supply voltage, output voltage, and output current of the TPSM8281x.

12 Layout

12.1 Layout Guidelines

A proper layout is critical for the operation of any switched mode power supply, especially at high switching frequencies. Therefore, the PCB layout of the TPSM8281x demands careful attention to ensure best performance. A poor layout can lead to issues like bad line and load regulation, instability, increased EMI radiation, and noise sensitivity. Refer to the *[Five Steps to a Great PCB Layout for a Step-Down Converter](http://www.ti.com/lit/SLYT614) [Technical Brief](http://www.ti.com/lit/SLYT614)* for a detailed discussion of general best practices. Specific recommendations for the device are listed below.

- The input capacitor should be placed as close as possible to the VIN and GND pins of the device. This is the most critical component placement. Route the input capacitor directly to the VIN and GND pins avoiding vias.
- Place the output capacitor ground close to the VOUT and GND pins and route it directly avoiding vias.
- Place the FB resistors, R1 and R2, and the feedforward capacitor C_{FF} close to the FB pin and place C_{SS} close to the SS/TR pin to minimize noise pickup.
- Place the R_{CF} resistor close to the COMP/FSET pin to minimize the parasitic capacitance.
- The recommended layout is implemented on the EVM and shown in its *[TPSM82810EVM-089 Evaluation](http://www.ti.com/lit/SLUUC44) [Module User's Guide](http://www.ti.com/lit/SLUUC44)* and in *Section 12.2*.
- The recommended land pattern for the TPSM8281x is shown at the end of this data sheet. For best manufacturing results, it is important to create the pads as solder mask defined (SMD), when some pins (such as VIN, VOUT, and GND) are connected to large copper planes. Using SMD pads keeps each pad the same size and avoids solder pulling the device during reflow.

12.2 Layout Example

图 **12-1. Example Layout**

12.2.1 Thermal Consideration

The TPSM8281x module temperature must be kept less than the maximum rating of 125°C. The following are three basic approaches for enhancing thermal performance:

- Improve the power dissipation capability of the PCB design.
- Improve the thermal coupling of the component to the PCB.
- Introduce airflow into the system.

To estimate the approximate module temperature of the TPSM8281x, apply the typical efficiency stated in this data sheet to the desired application condition to compute the power dissipation of the module. Then, calculate the module temperature rise by multiplying the power dissipation by its thermal resistance. For more details on how to use the thermal parameters in real applications, see the application notes: *[Thermal Characteristics of](https://www.ti.com/lit/pdf/SZZA017) [Linear and Logic Packages Using JEDEC PCB Designs](https://www.ti.com/lit/pdf/SZZA017)* and *[Semiconductor and IC Package Thermal Metrics](https://www.ti.com/lit/pdf/SPRA953)*.

The thermal values in $# 7.4$ $# 7.4$ used the recommended land pattern, shown at the end of this data sheet, including the 18 vias as they are shown. The TPSM8281x was simulated on a PCB defined by JEDEC 51-7. The 9 vias on the GND pins were connected to copper on other PCB layers, while the remaining 9 vias were not connected to other layers.

13 Device and Documentation Support

13.1 Device Support

13.1.1 第三方产品免责声明

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13.2 Documentation Support

13.2.1 Related Documentation

For related documentation see the following:

Texas Instruments, *[TPSM82810EVM-089 Evaluation Module](http://www.ti.com/lit/SLUUC44)*

13.3 接收文档更新通知

要接收文档更新通知,请导航至 [ti.com](https://www.ti.com) 上的器件产品文件夹。点击*订阅更新* 进行注册,即可每周接收产品信息更 改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

13.4 支持资源

TI E2E™ [支持论坛](https://e2e.ti.com)是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解 答或提出自己的问题可获得所需的快速设计帮助。

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13.5 Trademarks

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13.6 静电放电警告

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ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参 数更改都可能会导致器件与其发布的规格不相符。

13.7 术语表

TI [术语表](https://www.ti.com/lit/pdf/SLYZ022) 本术语表列出并解释了术语、首字母缩略词和定义。

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE OUTLINE

SIL0014B uSIP - 2.4 mm max height TM

MICRO SYSTEM IN PACKAGE

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. Pick and place nozzle \emptyset 1.3 mm or smaller recommended.
- 4. The package thermal pads must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

SIL0014B uSIP - 2.4 mm max height TM

MICRO SYSTEM IN PACKAGE

NOTES: (continued)

5. This package is designed to be soldered to thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

SIL0014B uSIP - 2.4 mm max height TM

MICRO SYSTEM IN PACKAGE

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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